onsemi

Silicon Carbide (SiC) Schottky Diode – EliteSiC, 20 A, 650 V, D2, D2PAK-2L

FFSB2065B-F085

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size & cost.

Features

- Max Junction Temperature 175°C
- Avalanche Rated 94 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

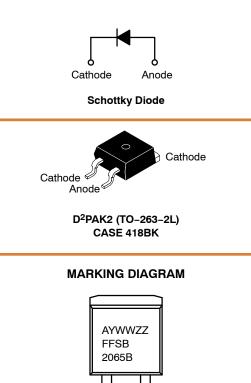
- Automotive HEV–EV Onboard Chargers
- Automotive HEV-EV DC-DC Converters

ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Paramete	Value	Unit			
Peak Repetitive Reverse Vo	650	V			
Single Pulse Avalanche Ene	94	mJ			
Continuous Rectified Forward Current @ $T_C < 142^{\circ}C$		20	A		
Continuous Rectified Forwa @ T _C < 135°C	22.8				
Non-Repetitive Peak Forward Surge Current	$T_C = 25^{\circ}C$, 10 µs	882	А		
	T _C = 150°C, 10 μs	798			
Non–Repetitive Forward Surge Current $T_C = 25^{\circ}C$	Half–Sine Pulse, t _p = 8.3 ms	84	A		
Power Dissipation	$T_{C} = 25^{\circ}C$	153	W		
	T _C = 150°C	25.5			
Operating Junction and Storage Temperature Range		–55 to +175	°C		
	Peak Repetitive Reverse Vo Single Pulse Avalanche End Continuous Rectified Forwa @ $T_C < 142^{\circ}C$ Continuous Rectified Forwa @ $T_C < 135^{\circ}C$ Non-Repetitive Peak Forward Surge Current Non-Repetitive Forward Surge Current $T_C = 25^{\circ}C$ Power Dissipation Operating Junction and Sto	$\label{eq:constraint} \begin{array}{c} @\ T_C < 142^\circ C \\ \hline \\ Continuous Rectified Forward Current \\ @\ T_C < 135^\circ C \\ \hline \\ Non-Repetitive Peak \\ Forward Surge Current \\ \hline \\ T_C = 150^\circ C, \ 10 \ \mu s \\ \hline \\ T_C = 150^\circ C, \ 10 \ \mu s \\ \hline \\ Non-Repetitive Forward \\ Surge Current T_C = 25^\circ C \\ \hline \\ Power Dissipation \\ \hline \\ \hline \\ Power Dissipation \\ \hline \\ T_C = 150^\circ C \\ \hline \\ \hline \\ T_C = 150^\circ C \\ \hline \\ \hline \\ Operating Junction \ and Storage Temperature \\ \hline \end{array}$	Peak Repetitive Reverse Voltage650Single Pulse Avalanche Energy (Note 1)94Continuous Rectified Forward Current (@ $T_C < 142^{\circ}C$ 20Continuous Rectified Forward Current (@ $T_C < 135^{\circ}C$ 22.8Non-Repetitive Peak Forward Surge Current $T_C = 25^{\circ}C$, 10 µs882Non-Repetitive Peak Forward Surge Current $T_C = 25^{\circ}C$ $T_C = 150^{\circ}C$, 10 µs798Non-Repetitive Forward Surge Current $T_C = 25^{\circ}C$ Half-Sine Pulse, $t_p = 8.3 \text{ ms}$ 84Power Dissipation $T_C = 25^{\circ}C$ 153 $T_C = 150^{\circ}C$ 25.5Operating Junction and Storage Temperature-55 to		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. E_{AS} of 94 mJ is based on starting T_J = 25°C, L = 0.5 mH, I_{AS} = 19.4 A, V = 50 V.



A = Assembly Plant Code YWW = Date Code (Year & Week) ZZ = Lot Code FFSB2065B = Specific Device Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

FFSB2065B-F085

THERMAL CHARACTERISTICS

Symbol	Parameter	Ratings	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max	0.98	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25° C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _F	Forward Voltage	$I_{\rm F} = 20 \text{ A}, \text{ T}_{\rm C} = 25^{\circ}\text{C}$	-	1.38	1.7	V
		$I_F = 20 \text{ A}, \text{ T}_C = 125^{\circ}\text{C}$	-	1.6	2.0	1
		I _F = 20 A, T _C = 175°C	-	1.72	2.4	
I _R	Reverse Current	$V_{R} = 650 \text{ V}, \text{ T}_{C} = 25^{\circ}\text{C}$	-	0.5	40	μΑ
		$V_{R} = 650 \text{ V}, \text{ T}_{C} = 125^{\circ}\text{C}$	-	1	80	1
		$V_{R} = 650 \text{ V}, \text{ T}_{C} = 175^{\circ}\text{C}$	-	2	160	1
Q _C	Total Capacitive Charge	V = 400 V	-	51	-	nC
C _{tot}	Total Capacitance	V _R = 1 V, f = 100 kHz	-	866	-	pF
		V _R = 300 V, f = 100 kHz	-	80	-	
		V _R = 600 V, f = 100 kHz	-	70	-	1

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

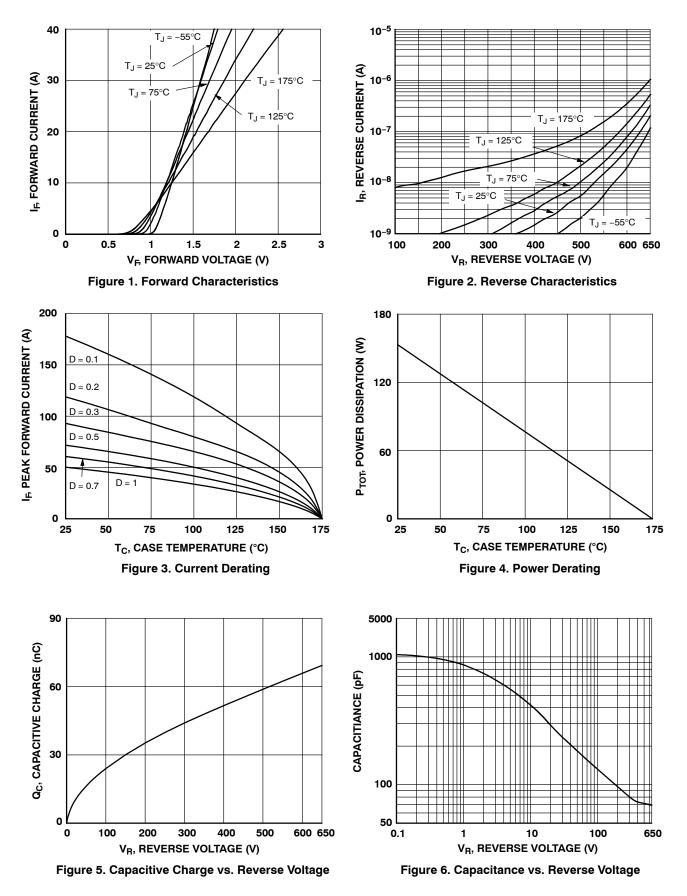
ORDERING INFORMATION

Part Number	Top Marking	Package	Shipping [†]
FFSB2065B-F085	FFSB2065B	D ² PAK2	800/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

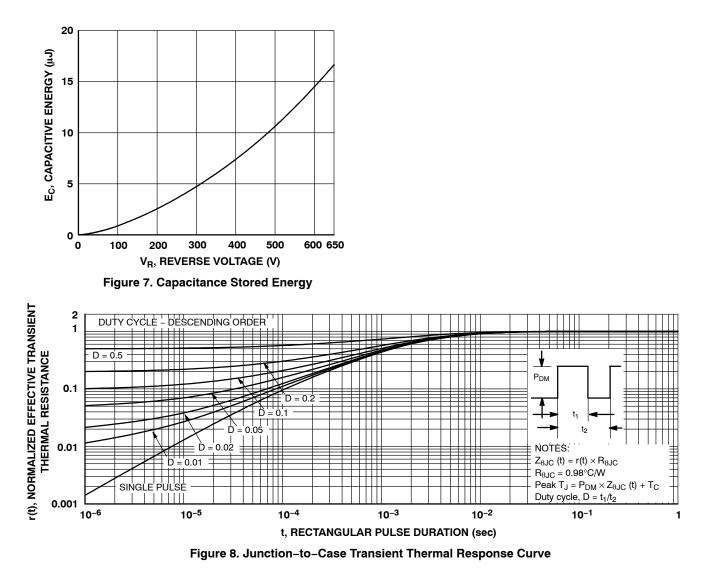
FFSB2065B-F085

TYPICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)



FFSB2065B-F085

TYPICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted) (continued)



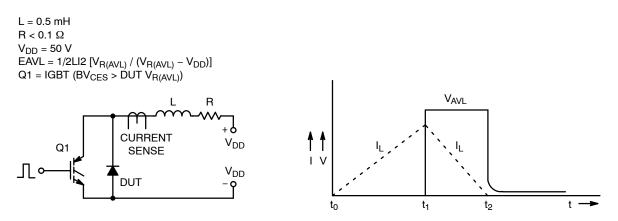
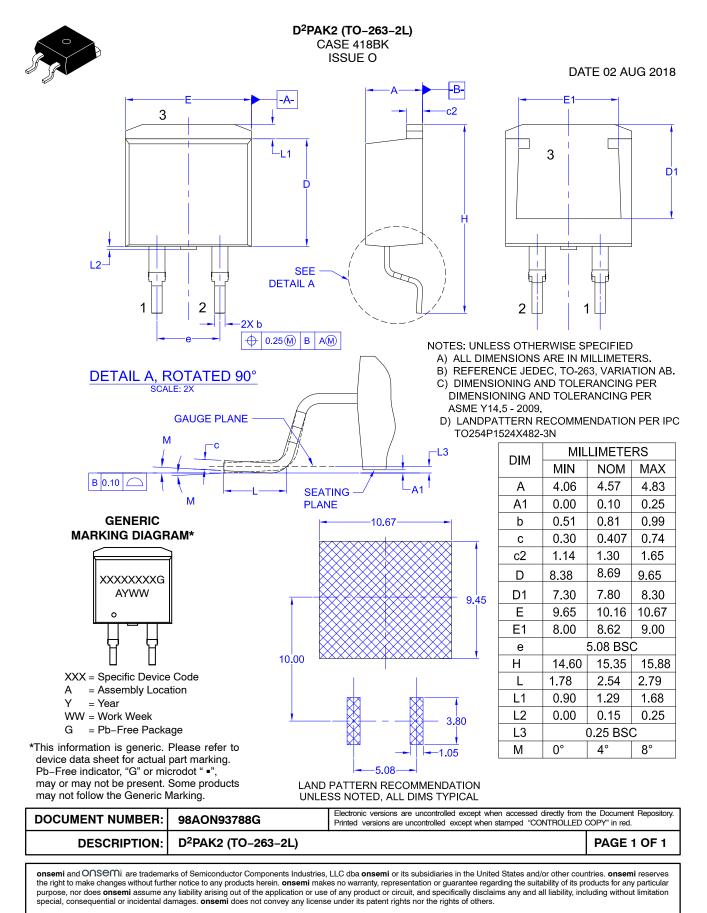


Figure 9. Unclamped Inductive Switching Test Circuit & Waveform

onsemí



onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and calcular performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

TECHNICAL SUPPORT

onsemi Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative